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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4F
Core Size	32-Bit Single-Core
Speed	160MHz
Connectivity	CANbus, CSIO, EBI/EMI, I²C, LINbus, SD, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	63
Program Memory Size	288KB (288K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 16x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 125°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/s6e2hg4e0agv20000

VBAT
The consumption power during the RTC operation can be reduced by supplying the power supply independent from the RTC (calendar circuit)/32 kHz oscillation circuit. The following circuits can also be used.

- RTC
- 32 kHz oscillation circuit
- Power-on circuit
- Back up register : 32 bytes
- Port circuit

Debug
- Serial Wire JTAG Debug Port (SWJ-DP)
- Embedded Trace Macrocells (ETM) provide comprehensive debug and trace facilities.

Unique ID
Unique value of the device (41-bit) is set.

Power Supply
Two Power Supplies

- Wide range voltage: VCC = 2.7 V to 5.5 V
- Power supply for VBAT: VBAT = 2.7 V to 5.5 V

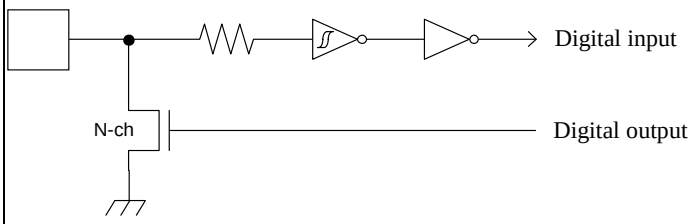
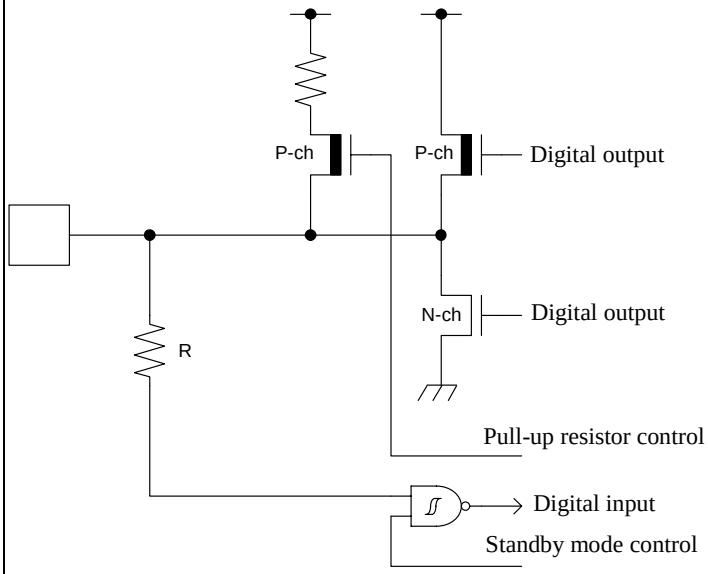
Pin Number				Pin Name	I/O Circuit Type	Pin State Type
LQFP120	LQFP100	LQFP80	FBGA121			
39	34	24	L4	P46 X0A	P	S
40	35	25	K4	P47 X1A	Q	T
41	36	26	K5	P48 VREGCTL	O	U
42	37	27	K6	P49 VWAKEUP	O	U
43	38	28	L5	VBAT	-	-
44	39	29	L6	C	-	-
45	40	30	L7	VSS	-	-
46	41	31	K7	VCC	-	-
47	42	32	J6	P4B TIOB1_0 SCS7_1 MAD03_0	E	I
48	43	33	J7	P4C TIOB2_0 SCK7_1 (SCL7_1) AIN1_2 MAD04_0	N	I
49	44	34	J8	P4D TIOB3_0 SOT7_1 (SDA7_1) BIN1_2 INT13_2 MAD05_0	N	K
50	45	35	K8	P4E TIOB4_0 SIN7_1 ZIN1_2 FRCK1_1 INT11_1 WKUP2 MAD06_0	I	Q
51	-	-	H6	P70 TIOA4_2 AIN0_1 IC13_1 TX0_0	E	I

Pin Number				Pin Name	I/O Circuit Type	Pin State Type
LQFP120	LQFP100	LQFP80	FBGA121			
89	74	-	B11	P20	F	M
				AN18		
				AIN1_1		
				INT05_0		
				MAD24_0		
				RTO25_0		
90	75	60	A11	VSS	-	-
91	76	61	A10	VCC	-	-
92	77	62	B9	P0E	L	I
				TIOB5_2		
				SCS6_1		
				IC13_0		
				S_CLK_0		
				MDQM1_0		
93	78	63	A9	P0D	L	I
				TIOA5_2		
				SCK6_1 (SCL6_1)		
				IC12_0		
				S_CMD_0		
				MDQM0_0		
94	79	64	C8	P0C	L	I
				TIOA6_1		
				SOT6_1 (SDA6_1)		
				IC11_0		
				S_DATA1_0		
				MALE_0		
95	80	65	B8	P0B	L	K
				TIOB6_1		
				SIN6_1		
				IC10_0		
				INT00_1		
				S_DATA0_0		
				MCSX0_0		
96	81	66	A8	P0A	L	K
				SIN1_0		
				FRCK1_0		
				INT12_2		
				S_DATA3_0		
				MCSX1_0		

Pin Number				Pin Name	I/O Circuit Type	Pin State Type
LQFP120	LQFP100	LQFP80	FBGA121			
97	82	67	D7	P09	M	N
				AN19		
		-		TRACED0		
		67		TIOA3_2		
				SOT1_0 (SDA1_0)		
				S_DATA2_0		
				MCSX5_0		
				IC23_1		
98	83	-	C7	P08	F	N
				AN20		
				TRACED1		
				TIOB3_2		
				SCK1_0 (SCL1_0)		
				MCSX4_0		
				IC22_1		
99	84	-	B7	P07	M	N
				AN21		
				TRACED2		
				TIOA0_2		
				SCK7_0 (SCL7_0)		
				MCLKOUT_0		
				IC21_1		
100	85	-	A7	P06	F	N
				AN22		
				TRACED3		
				TIOB0_2		
				SOT7_0 (SDA7_0)		
				MCSX3_0		
				IC20_1		
101	86	-	D6	P05	F	O
				AN23		
				ADTG_0		
				TRACECLK		
				SIN7_0		
				INT01_1		
				MCSX2_0		
				FRCK2_1		
102	87	68	B6	P04	E	G
				TDO		
				SWO		
103	88	69	C6	P03	E	G
				TMS		
				SWDIO		

Pin Function	Pin Name	Function Description	Pin No			
			LQFP 120	LQFP 100	LQFP 80	FBGA 121
Multi- function Timer 1	DTTI1X_0	Input signal controlling wave form generator outputs RTO10 to RTO15 of Multi-function timer 1.	8	8	8	E3
	DTTI1X_1		55	-	-	J9
	FRCK1_0	16-bit free-run timer ch.1 external clock input pin	96	81	66	A8
	FRCK1_1		50	45	35	K8
	IC10_0	16-bit input capture ch.1 input pin of Multi-function timer 1. ICxx describes channel number.	95	80	65	B8
	IC10_1		54	-	-	H8
	IC11_0		94	79	64	C8
	IC11_1		53	-	-	G7
	IC12_0		93	78	63	A9
	IC12_1		52	-	-	H7
	IC13_0		92	77	62	B9
	IC13_1		51	-	-	H6
	RTO10_0 (PPG10_0)	Wave form generator output pin of Multi-function timer 1. This pin operates as PPG10 when it is used in PPG1 output modes.	2	2	2	C1
	RTO10_1 (PPG10_1)		32	27	-	L2
	RTO11_0 (PPG10_0)	Wave form generator output pin of Multi-function timer 1. This pin operates as PPG10 when it is used in PPG1 output modes.	3	3	3	C2
	RTO11_1 (PPG10_1)		33	28	-	J3
	RTO12_0 (PPG12_0)	Wave form generator output pin of Multi-function timer 1. This pin operates as PPG12 when it is used in PPG1 output modes.	4	4	4	D1
	RTO12_1 (PPG12_1)		34	29	-	J5
	RTO13_0 (PPG12_0)	Wave form generator output pin of Multi-function timer 1. This pin operates as PPG12 when it is used in PPG1 output modes.	5	5	5	D2
	RTO13_1 (PPG12_1)		35	30	-	H5
	RTO14_0 (PPG14_0)	Wave form generator output pin of Multi-function timer 1. This pin operates as PPG14 when it is used in PPG1 output modes.	6	6	6	D3
	RTO14_1 (PPG14_1)		36	31	21	K3
	RTO15_0 (PPG14_0)	Wave form generator output pin of Multi-function timer 1. This pin operates as PPG14 when it is used in PPG1 output modes.	7	7	7	E2
	RTO15_1 (PPG14_1)		37	32	22	J4

Pin Function	Pin Name	Function Description	Pin No			
			LQFP 120	LQFP 100	LQFP 80	FBGA 121
Quadrature Position/ Revolution Counter 1	AIN1_0	QPRC ch.1 AIN input pin	10	-	-	F5
	AIN1_1		89	74	-	B11
	AIN1_2		48	43	33	J7
	BIN1_0	QPRC ch.1 BIN input pin	11	-	-	F6
	BIN1_1		88	73	-	C11
	BIN1_2		49	44	34	J8
	ZIN1_0	QPRC ch.1 ZIN input pin	12	-	-	G5
	ZIN1_1		87	72	-	C10
	ZIN1_2		50	45	35	K8
Quadrature Position/ Revolution Counter 2	AIN2_0	QPRC ch.2 AIN input pin	33	28	-	J3
	AIN2_1		119	99	79	A2
	AIN2_2		69	59	48	F9
	BIN2_0	QPRC ch.2 BIN input pin	34	29	-	J5
	BIN2_1		118	98	78	A3
	BIN2_2		68	58	47	F10
	ZIN2_0	QPRC ch.2 ZIN input pin	35	30	-	H5
	ZIN2_1		115	95	75	B3
	ZIN2_2		67	57	46	G8
Real-time clock	RTCCO_0	0.5 seconds pulse output pin of Real-time clock	115	95	75	B3
	RTCCO_1		64	54	43	H9
	RTCCO_2		23	18	13	H1
	SUBOUT_0	Sub clock output pin	115	95	75	B3
	SUBOUT_1		64	54	43	H9
	SUBOUT_2		23	18	13	H1
Low-Power Consumption Mode	WKUP0	Deep standby mode return signal input pin 0	116	96	76	B2
	WKUP1	Deep standby mode return signal input pin 1	14	9	9	E1
	WKUP2	Deep standby mode return signal input pin 2	50	45	35	K8
	WKUP3	Deep standby mode return signal input pin 3	69	59	48	F9
DAC	DA0	D/A converter ch.0 analog output pin	36	31	21	K3
	DA1	D/A converter ch.1 analog output pin	37	32	22	J4
VBAT	VREGCTL	On-board regulator control pin	41	36	26	K5
	VWAKEUP	The return signal input pin from a hibernation state	42	37	27	K6
SD I/F	S_CLK_0	SD memory card interface SD memory card clock output pin	92	77	62	B9
	S_CMD_0	SD memory card interface SD memory card command output	93	78	63	A9
	S_DATA1_0	SD memory card interface SD memory card data bus	94	79	64	C8
	S_DATA0_0		95	80	65	B8
	S_DATA3_0		96	81	66	A8
	S_DATA2_0		97	82	67	D7
	S_CD_0	SD memory card interface SD memory card detection pin	113	93	73	B4
	S_WP_0	SD memory card interface SD memory card write protection	114	94	74	C3

Type	Circuit	Remarks
C		– Open drain output – CMOS level hysteresis input
E		– CMOS level output – CMOS level hysteresis input – With pull-up resistor control – With standby mode control – Pull-up resistor : Approximately 50 kΩ – I_{OH} = -4 mA, I_{OL} = 4 mA – When this pin is used as an I^2C pin, the digital output P-ch transistor is always off.

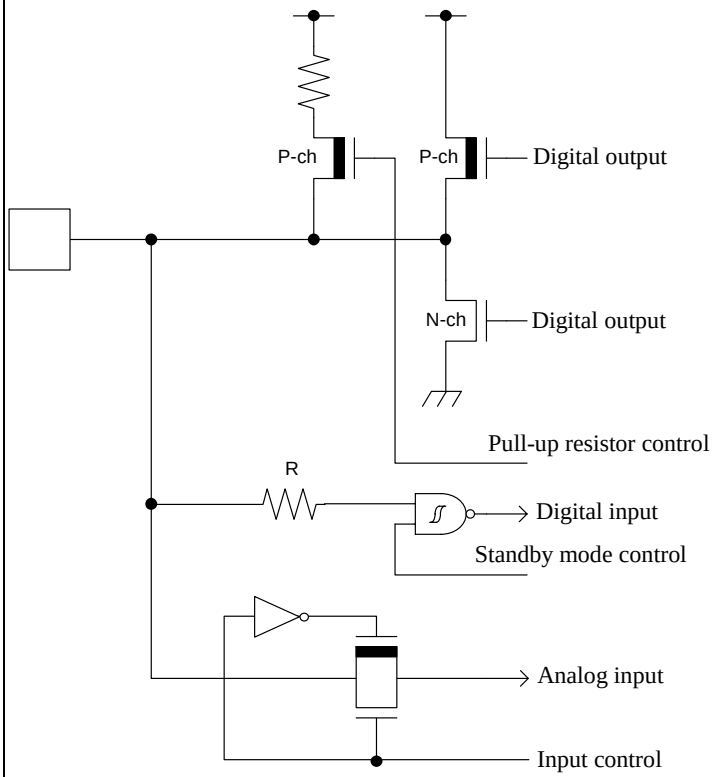
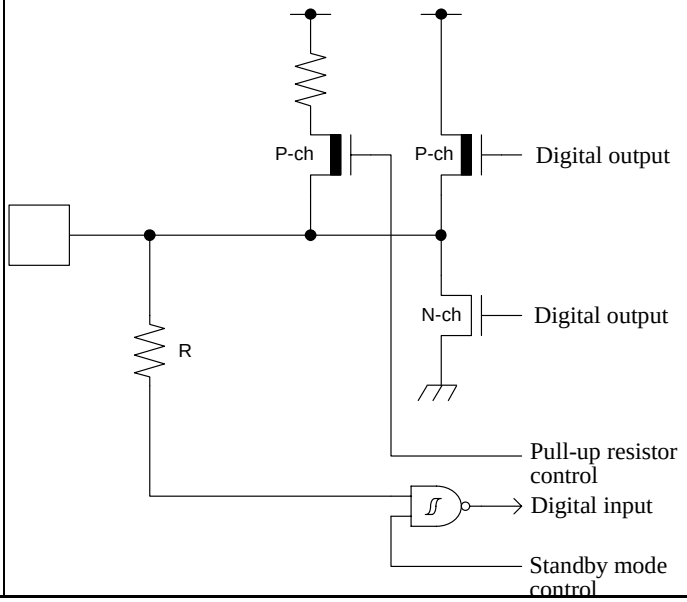
Type	Circuit	Remarks
F		– CMOS level output – CMOS level hysteresis input – With input control – Analog input – With pull-up resistor control – With standby mode control – Pull-up resistor : Approximately 50 kΩ – I_{OH} = -4 mA, I_{OL} = 4 mA – When this pin is used as an I^2C pin, the digital output P-ch transistor is always off.
G		– CMOS level output – CMOS level hysteresis input – With pull-up resistor control – With standby mode control – Pull-up resistor : Approximately 50 kΩ – I_{OH} = -12 mA, I_{OL} = 12 mA – When this pin is used as an I^2C pin, the digital output P-ch transistor is always off.

Table for Package Thermal Resistance and Maximum Permissible Power

Package	Printed Circuit Board	Thermal Resistance θja (°C/W)	Maximum Permissible Power (mW)	
			T_A=+85°C	T_A=+105°C
LQH080 (0.5mm pitch)	Single-layered both sides	82	488	244
	4 layers	56	714	357
LQI100 (0.5mm pitch)	Single-layered both sides	59	678	339
	4 layers	39	1026	513
LQM120 (0.5mm pitch)	Single-layered both sides	71	563	282
	4 layers	50	800	400
FDI121 (0.5mm pitch)	Single-layered both sides	63	635	317
	4 layers	37	1081	540

WARNING:

- *The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated under these conditions.*
  Any use of semiconductor devices will be under their recommended operating condition.
  Operation under any conditions other than these conditions may adversely affect reliability of device and could result in device failure.
  No warranty is made with respect to any use, operating conditions or combinations not represented on this data sheet. If you are considering application under any conditions other than listed herein, please contact sales representatives beforehand.

Calculation Method of Power Dissipation (Pd)

The power dissipation is shown in the following formula.

$$Pd = V_{CC} \times I_{CC} + \Sigma (I_{OL} \times V_{OL}) + \Sigma ((V_{CC}-V_{OH}) \times (-I_{OH}))$$

- I_{OL}: L level output current
- I_{OH}: H level output current
- V_{OL}: L level output voltage
- V_{OH}: H level output voltage

I_{CC} is a current consumed in device.
It can be analyzed as follows.

$$I_{CC} = I_{CC}(INT) + \Sigma I_{CC}(IO)$$

I_{CC}(INT): Current consumed in internal logic and memory, etc. through regulator

ΣI_{CC}(IO): Sum of current (I/O switching current) consumed in output pin

For I_{CC} (INT), it can be anticipated by (1) Current Rating in 3. DC Characteristics (This rating value does not include I_{CC} (IO) for a value at pin fixed).
For Icc (IO), it depends on system used by customers.
The calculation formula is shown below.

$$I_{CC}(IO) = (C_{INT} + C_{EXT}) \times V_{CC} \times fsw$$

- C_{INT}: Pin internal load capacitance
- C_{EXT}: External load capacitance of output pin
- f_{SW}: Pin switching frequency

Parameter	Symbol	Conditions	Capacitance Value
Pin internal load capacitance	C_{INT}	4 mA type	1.93 pF
		8 mA type	3.45 pF
		12 mA type	3.42 pF

Calculate I_{CC} (Max) as follows when the power dissipation can be evaluated by yourself.

1. Measure current value I_{CC} (Typ) at normal temperature (+25°C).
2. Add maximum leak current value I_{CC} (leak_max) at operating on a value in (1).

$$I_{CC}(Max) = I_{CC}(Typ) + I_{CC}(leak\_max)$$

Parameter	Symbol	Conditions	Current Value
Maximum leak current at operating	I_{CC}(leak_max)	T_J = +125°C	16.8 mA
		T_J = +105°C	8.6 mA
		T_J = +85°C	5.8 mA

13.4 AC Characteristics

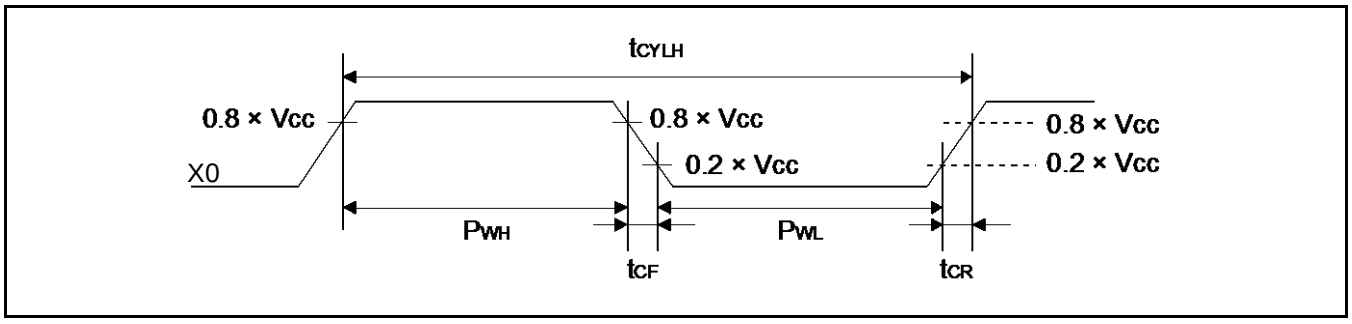
13.4.1 Main Clock Input Characteristics

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

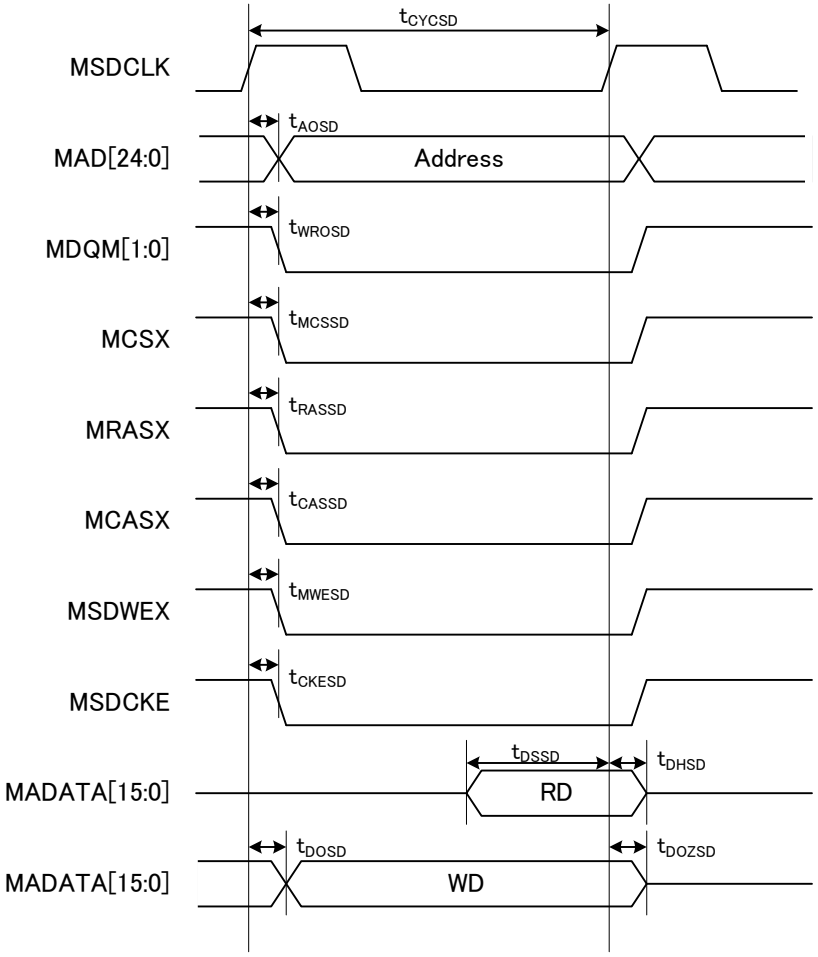
Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input frequency	f_{CH}	X0, X1	$V_{CC} \geq 4.5$ V	4	48	MHz	When crystal oscillator is connected
			$V_{CC} < 4.5$ V	4	20		
			$V_{CC} \geq 4.5$ V	4	48	MHz	When using external clock
			$V_{CC} < 4.5$ V	4	20		
Input clock cycle	t_{CYLH}		$V_{CC} \geq 4.5$ V	20.83	250	ns	When using external clock
			$V_{CC} < 4.5$ V	50	250		
Input clock pulse width	-		P_{WH}/t_{CYLH}, P_{WL}/t_{CYLH}	45	55	%	When using external clock
Input clock rising time and falling time	t_{CF}, t_{CR}		-	-	5	ns	When using external clock
Internal operating clock*1 frequency	f_{CC}	-	-	-	160	MHz	Base clock (HCLK/FCLK)
	f_{CP0}	-	-	-	80	MHz	APB0 bus clock*2
	f_{CP1}	-	-	-	160	MHz	APB1 bus clock*2
	f_{CP2}	-	-	-	80	MHz	APB2 bus clock*2
Internal operating clock*1 cycle time	t_{CYCC}	-	-	6.25	-	ns	Base clock (HCLK/FCLK)
	t_{CYCP0}	-	-	12.5	-	ns	APB0 bus clock*2
	t_{CYCP1}	-	-	6.25	-	ns	APB1 bus clock*2
	t_{CYCP2}	-	-	12.5	-	ns	APB2 bus clock*2

*1: For more information about each internal operating clock, see Chapter 2-1: Clock in FM4 Family Peripheral Manual Main part (002-04856).

*2: For about each APB bus which each peripheral is connected to, see 1. S6E2H Series Block Diagram" in this data sheet.



SDRAM Access

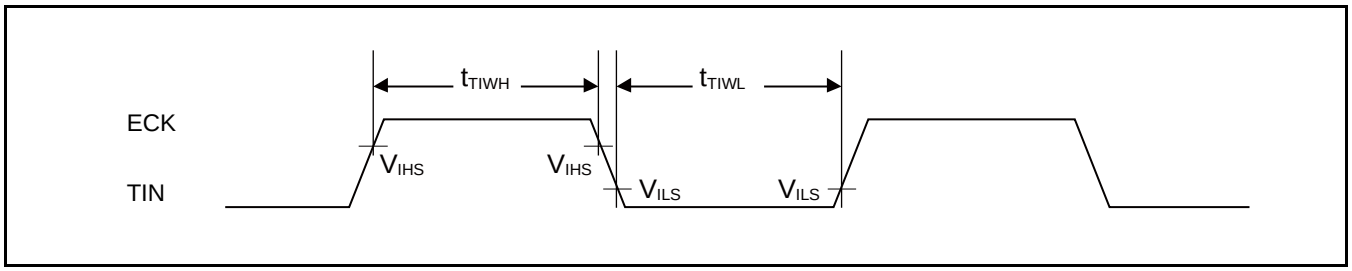


13.4.10 Base Timer Input Timing

Timer Input Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

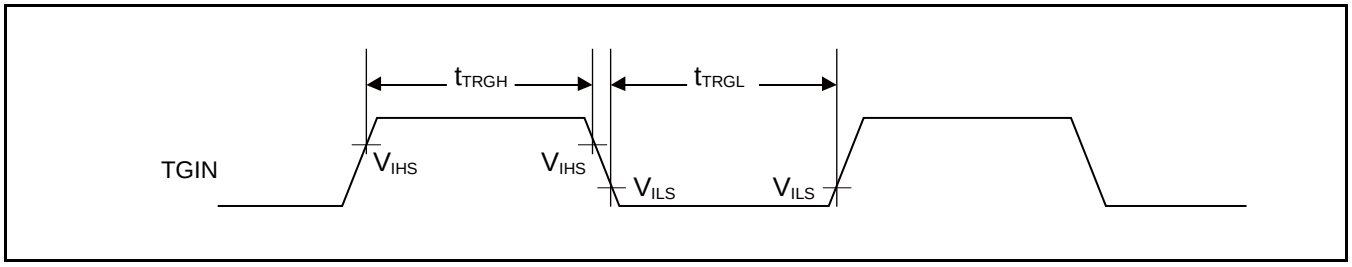
Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input pulse width	t_{TIWH}, t_{TIWL}	TIOAn/TIOBn (when using as ECK, TIN)	-	$2t_{CYCP}$	-	ns	



Trigger Input Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
Input pulse width	t_{TRGH}, t_{TRGL}	TIOAn/TIOBn (when using as TGIN)	-	$2t_{CYCP}$	-	ns	



Note:

- *t_{CYCP} indicates the APB bus clock cycle time.*
  About the APB bus number which the Base Timer is connected to, see 1. S6E2H Series Block Diagram in this data sheet.

When Using Synchronous Serial Chip Select (SCINV = 0, CSLVL = 1)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	V_{CC} < 4.5 V		V_{CC} ≥ 4.5 V		Unit
			Min	Max	Min	Max	
SCS↓→SCK↓setup time	t_{CSSI}	Internal shift clock operation	(*1)-50	(*1)+0	(*1)-50	(*1)+0	ns
SCK↑→SCS↑ hold time	t_{CSHI}		(*2)+0	(*2)+50	(*2)+0	(*2)+50	ns
SCS deselect time	t_{CSDI}		(*3)-50 +5t_{CYCP}	(*3)+50 +5t_{CYCP}	(*3)-50 +5t_{CYCP}	(*3)+50 +5t_{CYCP}	ns
SCS↓→SCK↓setup time	t_{CSSE}	External shift clock operation	3t_{CYCP}+30	-	3t_{CYCP}+30	-	ns
SCK↑→SCS↑ hold time	t_{CSHE}		0	-	0	-	ns
SCS deselect time	t_{CSDE}		3t_{CYCP}+30	-	3t_{CYCP}+30	-	ns
SCS↓→SUT delay time	t_{DSE}		-	40	-	40	ns
SCS↑→SUT delay time	t_{DEE}		0	-	0	-	ns

(*1): CSSU bit value×serial chip select timing operating clock cycle [ns]

(*2): CSHD bit value×serial chip select timing operating clock cycle [ns]

(*3): CSDS bit value×serial chip select timing operating clock cycle [ns]

Notes:

- *t_{CYCP} indicates the APB bus clock cycle time.*
  About the APB bus number which multi-function serial is connected to, see 1. S6E2H Series Block Diagram in this data sheet.
- *About CSSU, CSHD, CSDS, serial chip select timing operating clock, see FM4 Family Peripheral Manual Main part (002-04856).*
- *When the external load capacitance C_L = 30 pF.*

When Using High-speed Synchronous Serial Chip Select (SCINV = 0, CSLVL = 0)

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	V_{CC} < 4.5 V		V_{CC} ≥ 4.5 V		Unit
			Min	Max	Min	Max	
SCS↑→SCK↓setup time	t_{CSSI}	Internal shift clock operation	(*1)-20	(*1)+0	(*1)-20	(*1)+0	ns
SCK↑→SCS↓ hold time	t_{CSHI}		(*2)+0	(*2)+20	(*2)+0	(*2)+20	ns
SCS deselect time	t_{CSDI}		(*3)-20 +5t_{CYCP}	(*3)+20 +5t_{CYCP}	(*3)-20 +5t_{CYCP}	(*3)+20 +5t_{CYCP}	ns
SCS↑→SCK↓setup time	t_{CSSE}	External shift clock operation	3t_{CYCP}+15	-	3t_{CYCP}+15	-	ns
SCK↑→SCS↓ hold time	t_{CSHE}		0	-	0	-	ns
SCS deselect time	t_{CSDE}		3t_{CYCP}+15	-	3t_{CYCP}+15	-	ns
SCS↑→SOT delay time	t_{DSE}		-	25	-	25	ns
SCS↓→SOT delay time	t_{DEE}		0	-	0	-	ns

(*1): CSSU bit value×serial chip select timing operating clock cycle [ns]

(*2): CSHD bit value×serial chip select timing operating clock cycle [ns]

(*3): CSDS bit value×serial chip select timing operating clock cycle [ns]

Notes:

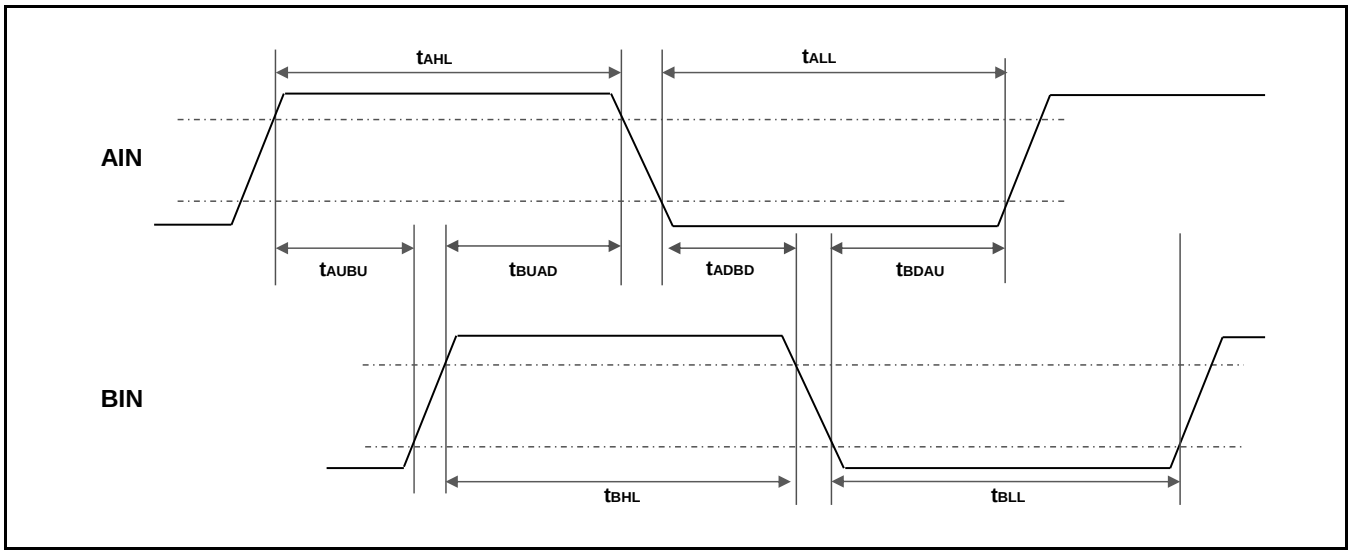
- *t_{CYCP} indicates the APB bus clock cycle time.*
  About the APB bus number which multi-function serial is connected to, see 1. S6E2H Series Block Diagram in this data sheet.
- *About CSSU, CSHD, CSDS, serial chip select timing operating clock, see FM4 Family Peripheral Manual Main part (002-04856).*
- *When the external load capacitance C_L = 30 pF.*

13.4.13 Quadrature Position/Revolution Counter Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Conditions	Value		Unit
			Min	Max	
AIN pin H width	t_{AHL}	-	$2t_{CYCP}$*	-	ns
AIN pin L width	t_{ALL}	-			
BIN pin H width	t_{BHL}	-			
BIN pin L width	t_{BLL}	-			
BIN rising time from AIN pin H level	t_{AUBU}	PC_Mode2 or PC_Mode3			
AIN falling time from BIN pin H level	t_{BUAD}	PC_Mode2 or PC_Mode3			
BIN falling time from AIN pin L level	t_{ADBD}	PC_Mode2 or PC_Mode3			
AIN rising time from BIN pin L level	t_{BDAU}	PC_Mode2 or PC_Mode3			
AIN rising time from BIN pin H level	t_{BUAU}	PC_Mode2 or PC_Mode3			
BIN falling time from AIN pin H level	t_{AUBD}	PC_Mode2 or PC_Mode3			
AIN falling time from BIN pin L level	t_{BDAD}	PC_Mode2 or PC_Mode3			
BIN rising time from AIN pin L level	t_{ADBU}	PC_Mode2 or PC_Mode3			
ZIN pin H width	t_{ZHL}	QCR:CGSC="0"			
ZIN pin L width	t_{ZLL}	QCR:CGSC="0"			
AIN/BIN rising and falling time from determined ZIN level	t_{ZABE}	QCR:CGSC="1"			
Determined ZIN level from AIN/BIN rising and falling time	t_{ABEZ}	QCR:CGSC="1"			

*: t_{CYCP} indicates the APB bus clock cycle time except stop when in Stop mode, in timer mode.
About the APB bus number which Quadrature Position/Revolution Counter is connected to, see 1. S6E2H Series Block Diagram in this data sheet.



High-Speed Mode

■Clock CLK (All values are referred to V_{IH} and V_{IL})

(V_{CC} = 2.7V to 3.6V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Remarks
				Min	Max	
Clock frequency Data Transfer Mode	f_{PP}	S_CLK	C_{CARD} ≤ 10 pF (1 card)	0	40	MHz
Clock low time	t_{WL}	S_CLK		7	-	ns
Clock high time	t_{WH}	S_CLK		7	-	ns
Clock rising time	t_{TLH}	S_CLK		-	3	ns
Clock falling time	t_{THL}	S_CLK		-	3	ns

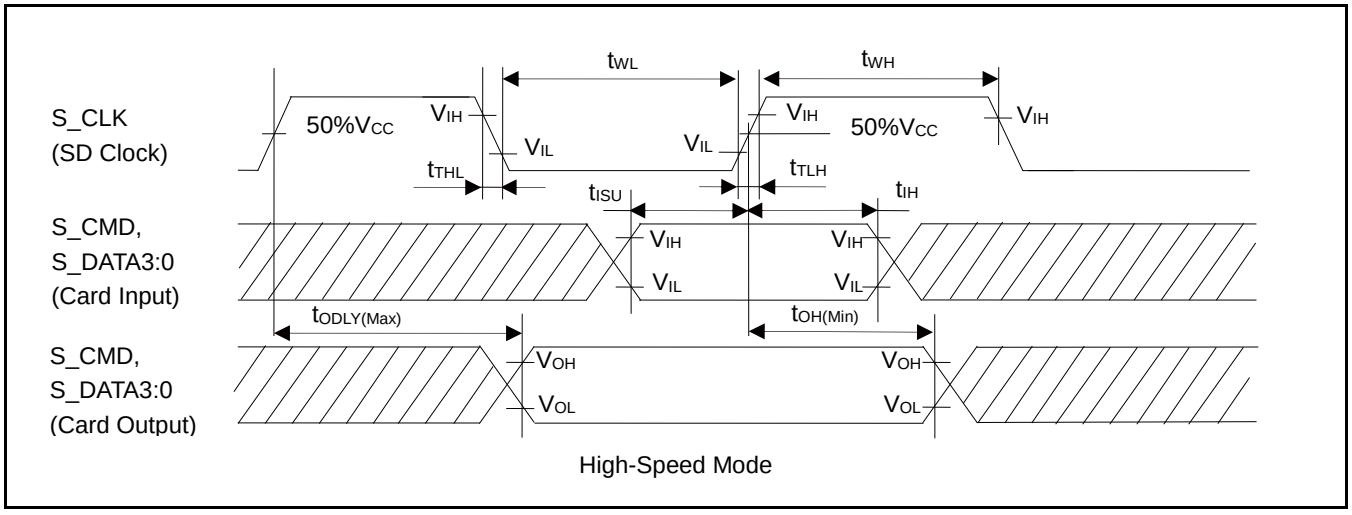
■Card Inputs CMD, DAT (referenced to Clock CLK)

Parameter	Symbol	Pin Name	Conditions	Value		Remarks
				Min	Max	
Input set-up time	t_{ISU}	S_CMD, S_DATA3:0	C_{CARD} ≤ 10 pF (1 card)	8	-	ns
Input hold time	t_{IH}	S_CMD, S_DATA3:0		2	-	ns

■Card Outputs CMD, DAT (referenced to Clock CLK)

Parameter	Symbol	Pin Name	Conditions	Value		Remarks
				Min	Max	
Output Delay time during Data Transfer Mode	t_{ODLY}	S_CMD, S_DATA3:0	C_L ≤ 40 pF (1 card)	-	22	ns
Output Hold time	t_{OH}	S_CMD, S_DATA3:0	C_L ≥ 15 pF (1 card)	2.5	-	ns
Total System capacitance for each line*	C_L	-	1 card	-	40	pF

*: In order to satisfy severe timing, host shall drive only one card.



High-Speed Mode

Notes:

- *The Card Input corresponds to the Host Output and the Card Output corresponds to the Host Input because this model is the Host.*
- *For more information about clock frequency (f_{PP}), see Chapter 15: SD card Interface in FM4 Family Peripheral Manual Main Part (002-04856).*

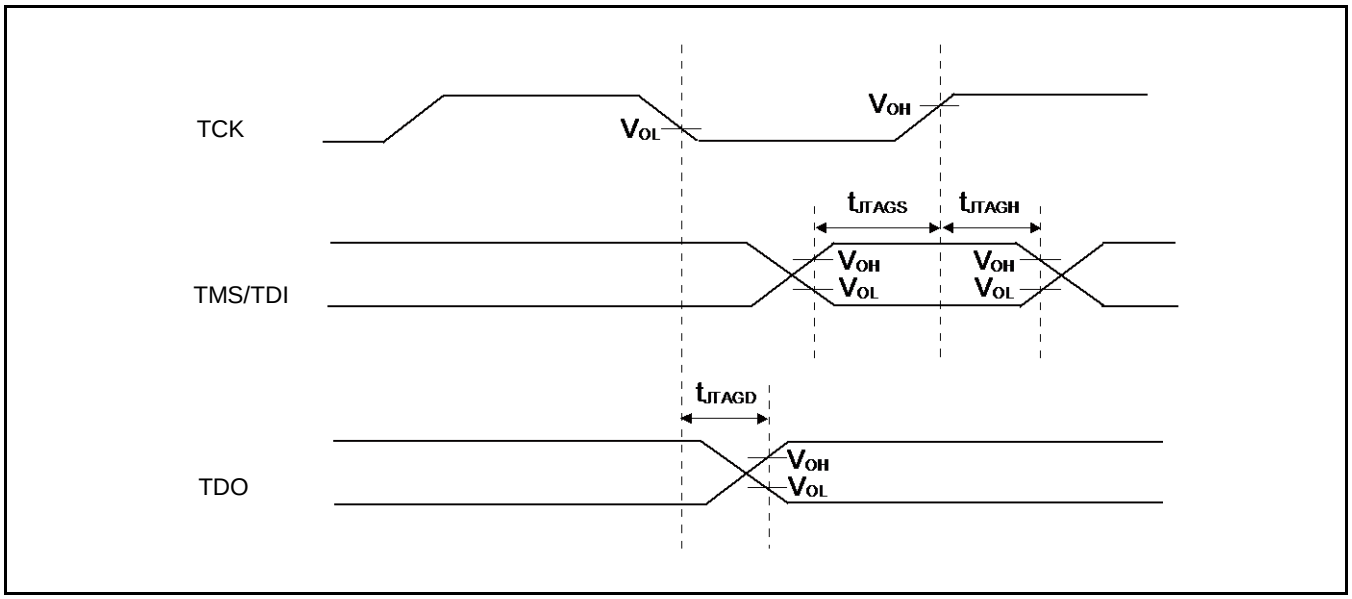
13.4.17 JTAG Timing

(V_{CC} = 2.7V to 5.5V, V_{SS} = 0V)

Parameter	Symbol	Pin Name	Conditions	Value		Unit	Remarks
				Min	Max		
TMS, TDI setup time	t_{JTAGS}	TCK, TMS, TDI	$V_{CC} \geq 4.5$ V	15	-	ns	
			$V_{CC} < 4.5$ V				
TMS, TDI hold time	t_{JTAGH}	TCK, TMS, TDI	$V_{CC} \geq 4.5$ V	15	-	ns	
			$V_{CC} < 4.5$ V				
TDO delay time	t_{JTAGD}	TCK, TDO	$V_{CC} \geq 4.5$ V	-	25	ns	
			$V_{CC} < 4.5$ V	-	45		

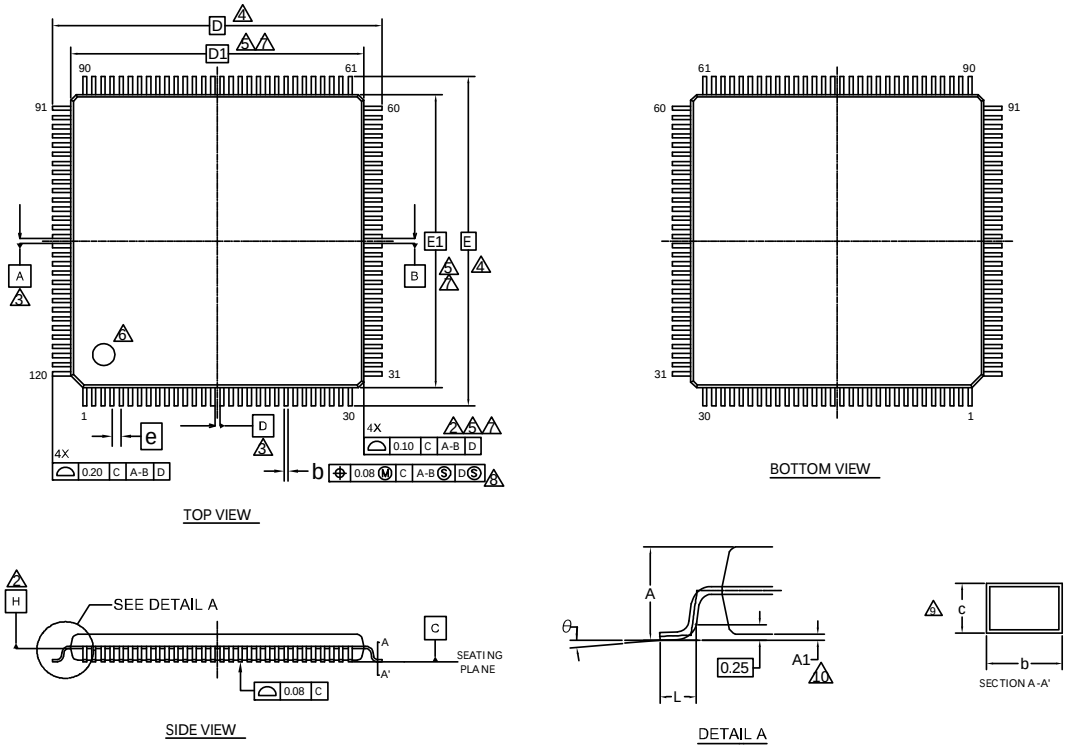
Note:

- *When the external load capacitance C_L= 30 pF.*



15. Package Dimensions

Package Type	Package Code
LQFP 120	LQM120



SYMBOL	DIMENSIONS		
	MIN.	NOM.	MAX.
A	—	—	1.70
A1	0.05	—	0.15
b	0.17	0.22	0.27
c	0.115	—	0.195
D	18.00 BSC		
D1	16.00 BSC		
e	0.50 BSC		
E	18.00 BSC		
E1	16.00 BSC		
L	0.45	0.60	0.75
θ	0°	—	8°

NOTES

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. DATUM PLANE H IS LOCATED AT THE BOTTOM OF THE MOLD PARTING LINE COINCIDENT WITH WHERE THE LEAD EXITS THE BODY.
3. DATUMS A-B AND D TO BE DETERMINED AT DATUM PLANE H.
4. TO BE DETERMINED AT SEATING PLANE C.
5. DIMENSIONS D1 AND E1 DO NOT INCLUDE MOLD PROTRUSION. ALLOWABLE PROTRUSION IS 0.25mm PRE SIDE. DIMENSIONS D1 AND E1 INCLUDE MOLD MISMATCH AND ARE DETERMINED AT DATUM PLANE H.
6. DETAILS OF PIN 1 IDENTIFIER ARE OPTIONAL BUT MUST BE LOCATED WITHIN THE ZONE INDICATED.
7. REGARDLESS OF THE RELATIVE SIZE OF THE UPPER AND LOWER BODY SECTIONS. DIMENSIONS D1 AND E1 ARE DETERMINED AT THE LARGEST FEATURE OF THE BODY EXCLUSIVE OF MOLD FLASH AND GATE BURRS. BUT INCLUDING ANY MISMATCH BETWEEN THE UPPER AND LOWER SECTIONS OF THE MOLDER BODY.
8. DIMENSION b DOES NOT INCLUDE DAMBER PROTRUSION. THE DAMBAR PROTRUSION (S) SHALL NOT CAUSE THE LEAD WIDTH TO EXCEED b MAXIMUM BY MORE THAN 0.08mm. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE LEAD FOOT.
9. THESE DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10mm AND 0.25mm FROM THE LEAD TIP.
10. A1 IS DEFINED AS THE DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
11. JEDEC SPECIFICATION NO. REF: N/A.

PACKAGE OUTLINE, 120 LEAD LQFP
18.0X18.0X1.7 MM LQM120 REV**

002-16172 **

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